

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 x 10A
V_{RRM}	100V
V_F (max)	0.7V
T_j (max)	175°C

FEATURES

- Negligible switching losses
- Low forward voltage drop
- Low capacitance
- High reverse avalanche surge capability

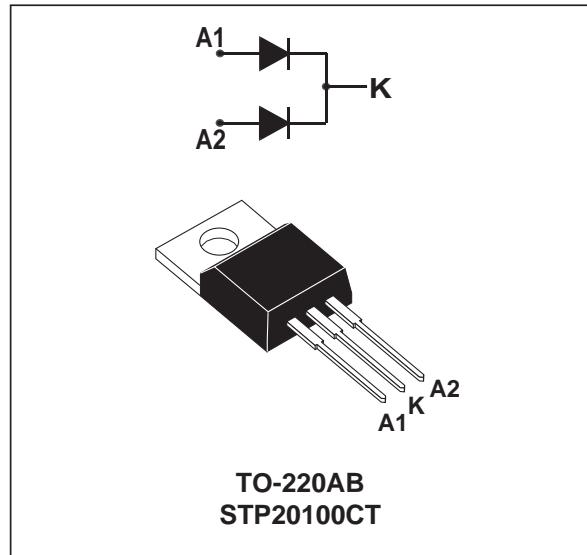
DESCRIPTION

High voltage dual Schottky rectifier suited for switchmode power supplies and other power converters. Packaged in TO-220AB, this device is intended for use in medium voltage operation, and particularly, in high frequency circuitries where low switching losses and low noise are required.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			100	V
$I_{F(RMS)}$	RMS forward current		Per diode	30	A
$I_{F(AV)}$	Average forward current $\delta = 0.5$	$T_c=110^\circ\text{C}$ $V_R = 60\text{V}$	Per diode Per device	10 20	A A
I_{FSM}	Surge non repetitive forward current	$tp=10\text{ms}$ sinusoidal	Per diode	200	A
I_{RRM}	Repetitive peak reverse current	$tp=2\mu\text{s}$ $F=1\text{KHz}$	Per diode	1	A
I_{RSR}	Non repetitive peak reverse current	$tp=100\mu\text{s}$	Per diode	1	A
T_{stg}	Storage temperature range			- 65 to + 175	°C
T_j	Maximum junction temperature (*)			175	°C
dV/dt	Critical rate of rise of reverse voltage			1000	V/ μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink



STPS20100CT

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th} (j-c)	Junction to case	Per diode	1.6
		Total	0.9
R _{th} (c)	Coupling	0.15	°C/W

When the diodes 1 and 2 are used simultaneously :

$$T_j - T_c(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

ELECTRICAL CHARACTERISTICS (Per diode)

STATIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I _R *	Reverse leakage current	V _R = V _{RRM}	T _j = 25°C			150	µA
			T _j = 125°C			100	mA
V _F **	Forward voltage drop	IF = 20A	T _j = 125°C		0.85	V	
		IF = 10A	T _j = 125°C		0.60		
		IF = 20A	T _j = 25°C		0.70		

Pulse test : * tp = 5 ms, duty cycle < 2 %

** tp = 380 µs, duty cycle < 2 %

To evaluate the conduction losses use the following equation :

$$P = 0.55 \times I_{F(AV)} + 0.015 \times I_F^2(\text{RMS})$$

Fig. 1 : Average forward power dissipation versus average forward current. (Per diode)

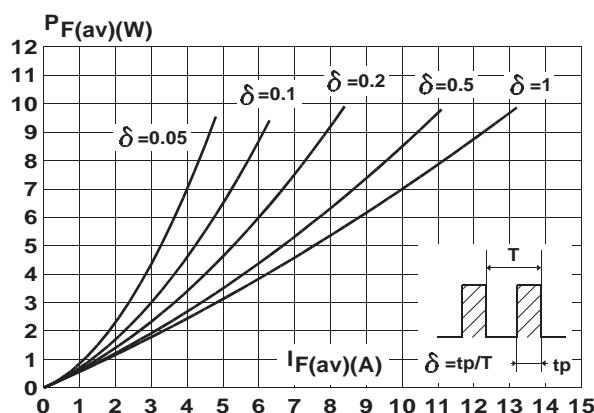


Fig. 2 : Average current versus ambient temperature. (duty cycle : 0.5) (Per diode)

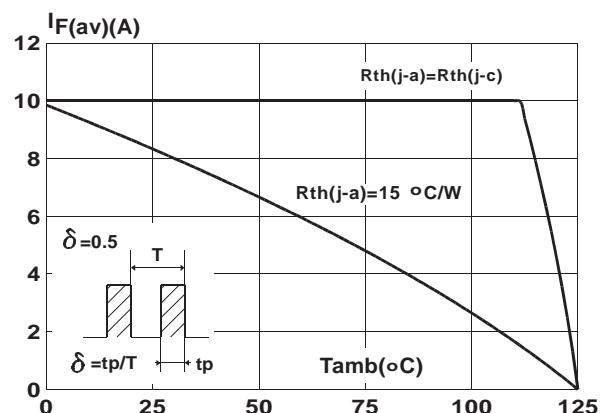


Fig. 3 : Non repetitive surge peak forward current versus overload duration.
(Maximum values) (Per diode)

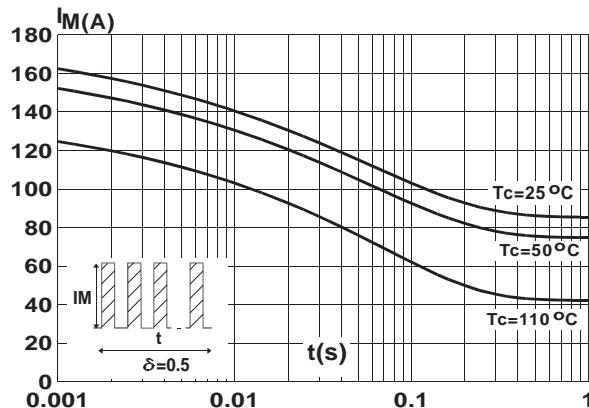


Fig. 5 : Reverse leakage current versus reverse voltage applied. (Typical values) (Per diode)

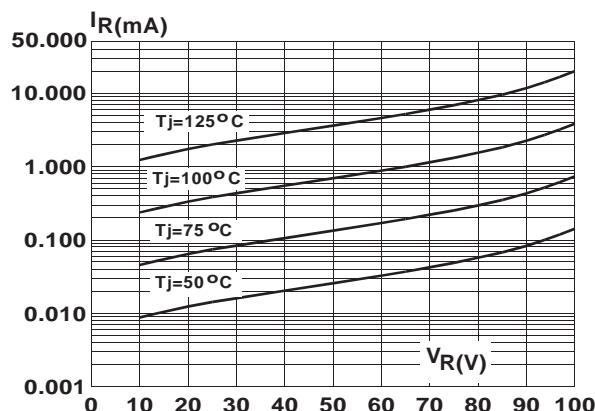


Fig. 7 : Forward voltage drop versus forward current. (Maximum values) (Per diode)

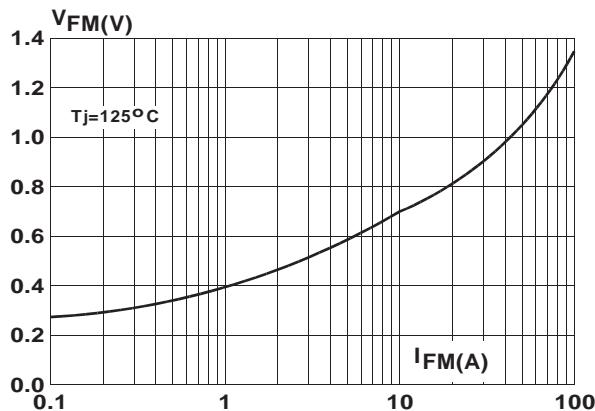


Fig. 4 : Relative variation of thermal transient impedance junction to case versus pulse duration.

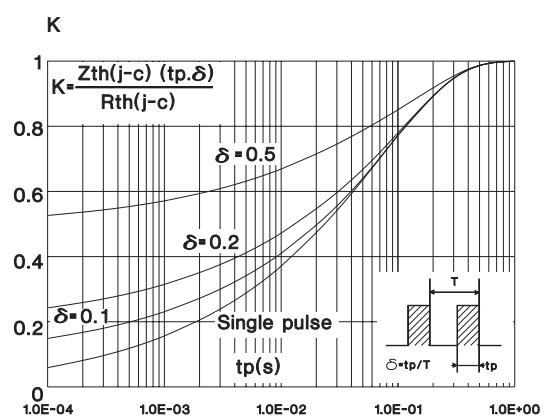
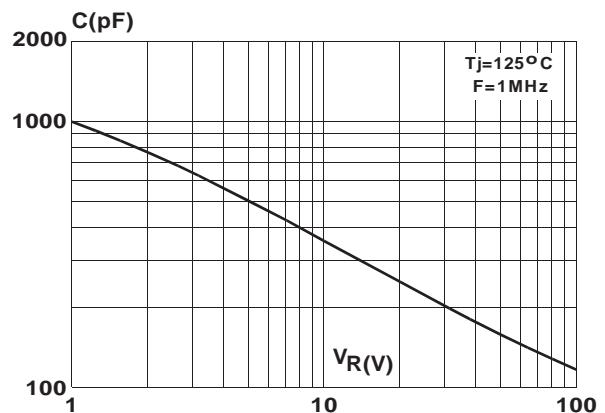
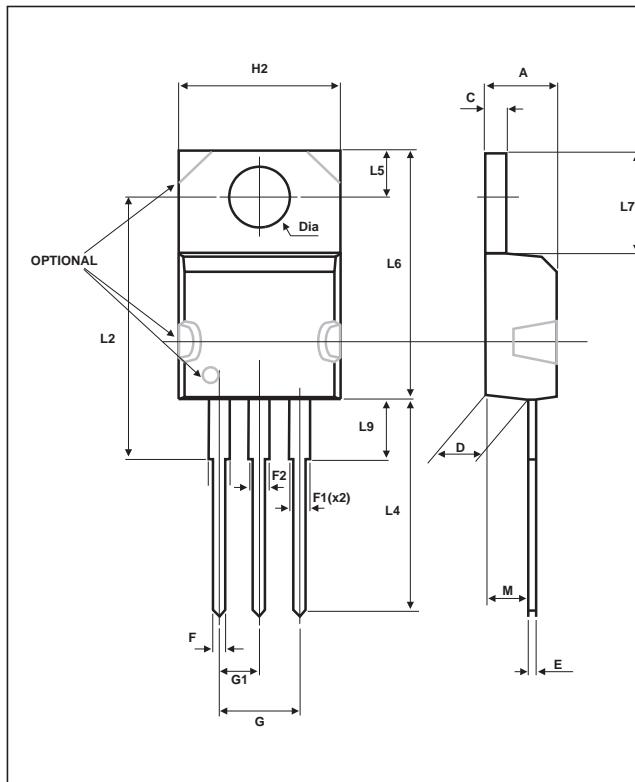


Fig. 6 : Junction capacitance versus reverse voltage applied. (Typical values) (Per diode)



STPS20100CT

PACKAGE MECHANICAL DATA TO-220AB (JEDEC outline)



The technical drawing illustrates the physical dimensions of the TO-220AB package. It shows a top-down view of the package body with lead wires extending downwards. Various dimensions are labeled: H2, L2, Dia, L5, L6, L7, A, C, D, E, F, F1, F2, G, G1, L4, L9, M, and L2. An 'OPTIONAL' feature is indicated by a bracket on the left side. The right side of the drawing contains a table of dimensions.

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.60	0.169	0.181
C	1.22	1.32	0.048	0.052
D	2.40	2.72	0.094	0.107
E	0.33	0.70	0.013	0.028
F	0.61	0.93	0.024	0.037
F1	1.14	1.70	0.045	0.067
F2	1.14	1.70	0.045	0.067
G	4.95	5.15	0.195	0.202
G1	2.40	2.70	0.094	0.106
H2	10.00	10.40	0.394	0.409
L2	16.00	Typ.	0.630	Typ.
L4	13.00	14.00	0.512	0.551
L5	2.65	2.95	0.104	0.116
L6	14.80	15.75	0.583	0.620
L7	6.20	6.60	0.244	0.260
L9	3.40	3.94	0.134	0.155
M	2.60	Typ.	0.102	Typ.
Dia.	3.75	3.89	0.148	0.153

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20100CT	STPS20100CT	TO-220AB	2.23g	50	Tube

- Cooling method : by conduction (C)
- Recommended torque value : 0.55N.m.
- Maximum torque value : 0.7N.m.
- Epoxy meets UL94,V0

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